

1SS106

Silicon Schottky Barrier Diode for Various Detector,
High Speed Switching

HITACHI

ADE-208-153A (Z)

Rev. 1

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勝特力材料 886-3-5753170
勝特力电子(上海) 86-21-54151736
勝特力电子(深圳) 86-755-83298787
[Http://www.100y.com.tw](http://www.100y.com.tw)

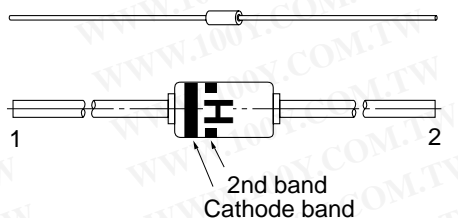
Features

- Detection efficiency is very good.
- Small temperature coefficient.
- High reliability with glass seal.

Ordering Information

Type No.	Cathode	2nd band	Mark	Package Code
1SS106	White	White	H	DO-35

Outline



Absolute Maximum Ratings (Ta = 25°C)

Item	Symbol	Value	Unit
Reverse voltage	V_R	10	V
Average rectified current	I_O	30	mA
Junction temperature	T_j	125	°C
Storage temperature	T_{stg}	-55 to +125	°C

Electrical Characteristics (Ta = 25°C)

Item	Symbol	Min	Typ	Max	Unit	Test Condition
Forward current	I_F	4.5	—	—	mA	$V_F = 1V$
Reverse current	I_R	—	—	70	μA	$V_R = 6V$
Capacitance	C	—	—	1.5	pF	$V_R = 1V, f = 1MHz$
Rectifier efficiency	η	70	—	—	%	$V_{in} = 2V_{rms}, f = 40MHz, R_L = 5k\Omega, C_L = 20pF$
ESD-Capability ^{*1}	—	100	—	—	V	C = 200pF, Both forward and reverse direction 1 pulse.

Notes: 1. Failure criterion; $I_R \geq 140\mu A$ at $V_R = 6V$

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Main Characteristic

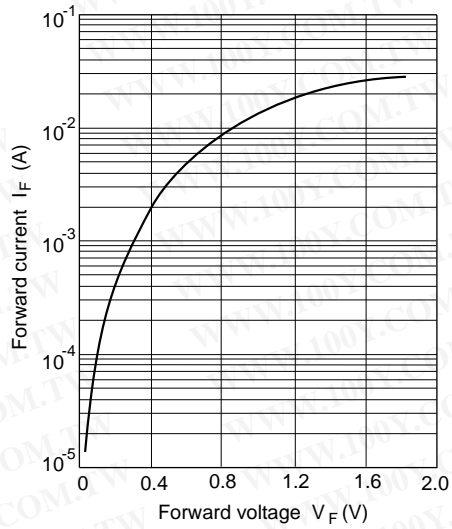


Fig.1 Forward current Vs. Forward voltage

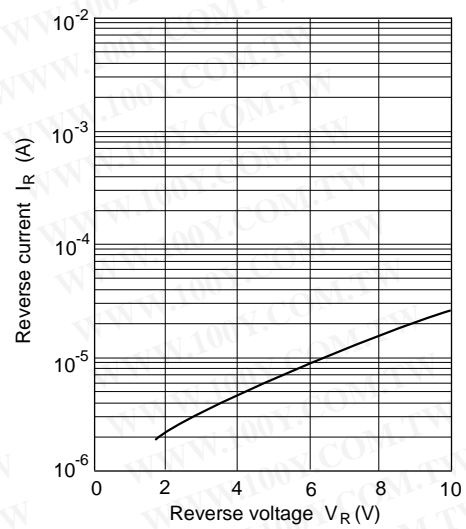


Fig.2 Reverse current Vs. Reverse voltage

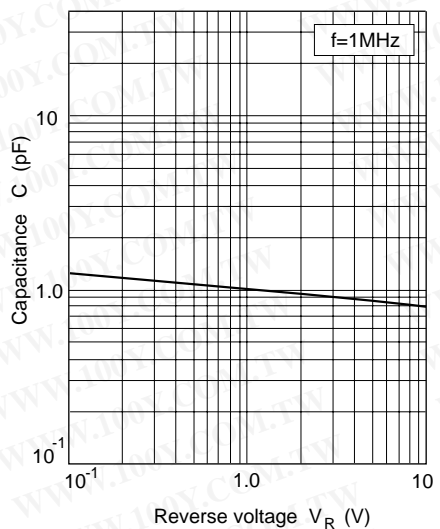


Fig.3 Capacitance Vs. Reverse voltage

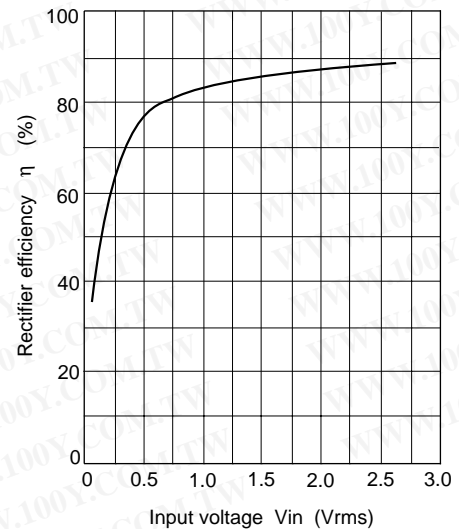
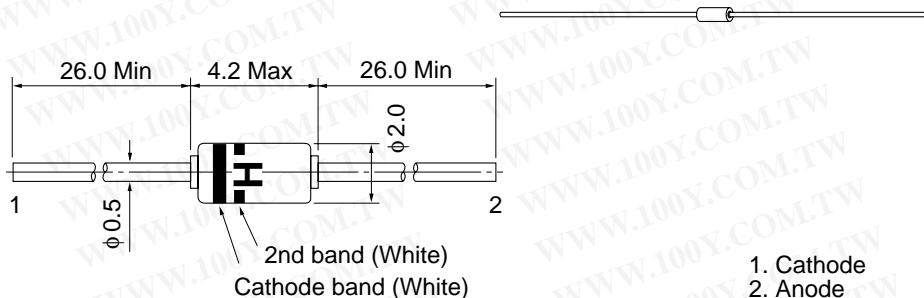


Fig.4 Rectifier efficiency Vs. Input voltage V_{in}

Package Dimensions



Hitachi Code	DO-35
JEDECCode	DO-35
EIAJCode	SC-48
Weight(g)	0.13

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